

#### Is Now Part of



## ON Semiconductor®

## To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to Fairchild <a href="guestions@onsemi.com">guestions@onsemi.com</a>.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer

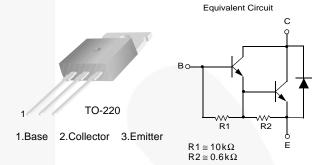


November 2014

# TIP110 / TIP111 / TIP112 NPN Epitaxial Silicon Darlington Transistor

#### **Features**

- Monolithic Construction with Built-in Base-Emitter Shunt Resistors
- Complementary to TIP115 / TIP116 / TIP117
- High DC Current Gain:  $h_{FE} = 1000 @ V_{CE} = 4 V, I_{C} = 1 A (Minimum)$
- Low Collector-Emitter Saturation Voltage
- Industrial Use



## **Ordering Information**

| Part Number | Top Mark | Package                  | Packing Method |
|-------------|----------|--------------------------|----------------|
| TIP110      | TIP110   | TO-220 3L (Single Gauge) | Bulk           |
| TIP110TU    | TIP110   | TO-220 3L (Single Gauge) | Rail           |
| TIP111TU    | TIP111   | TO-220 3L (Single Gauge) | Rail           |
| TIP112      | TIP112   | TO-220 3L (Single Gauge) | Bulk           |
| TIP112TU    | TIP112   | TO-220 3L (Single Gauge) | Rail           |

#### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_C = 25^{\circ}C$  unless otherwise noted.

| Symbol                | Parameter                 |        | Value      | Unit |
|-----------------------|---------------------------|--------|------------|------|
|                       |                           | TIP110 | 60         |      |
| V <sub>CBO</sub> Coll | Collector-Base Voltage    | TIP111 | 80         | V    |
|                       |                           | TIP112 | 100        |      |
| V <sub>CEO</sub> C    |                           | TIP110 | 60         | V    |
|                       | Collector-Emitter Voltage | TIP111 | 80         |      |
|                       |                           | TIP112 | 100        |      |
| V <sub>EBO</sub>      | Emitter-Base Voltage      |        | 5          | V    |
| I <sub>C</sub>        | Collector Current (DC)    |        | 2          | Α    |
| I <sub>CP</sub>       | Collector Current (Pulse) |        | 4          | Α    |
| I <sub>B</sub>        | Base Current (DC)         |        | 50         | mA   |
| TJ                    | Junction Temperature      |        | 150        | °C   |
| T <sub>STG</sub>      | Storage Temperature Range |        | -65 to 150 | °C   |

## **Thermal Characteristics**

Values are at  $T_C = 25^{\circ}C$  unless otherwise noted.

| Symbol | Parameter Valu                                |    | Unit |
|--------|---|----|------|
| Po     | Collector Dissipation (T <sub>A</sub> = 25°C) | 2  | W    |
| PC     | Collector Dissipation (T <sub>C</sub> = 25°C) | 50 | VV   |

## **Electrical Characteristics**(1)

Values are at  $T_C = 25$ °C unless otherwise noted.

| Symbol   | Parameter                            |   | Conditions   | Min. | Max. | Unit |
|--|--------------------------------------|---|--|------|------|------|
| V <sub>CEO</sub> (sus)                                     | Collector-Emitter Sustaining Voltage | TIP110                                  | I <sub>C</sub> = 30 mA, I <sub>B</sub> = 0         | 60   |      | V    |
|  |                                      | TIP111                                  |  | 80   |      |      |
|  |                                      | TIP112                                  |  | 100  |      |      |
|  | Collector Cut-Off Current            | TIP110                                  | $V_{CE} = 30 \text{ V}, I_{B} = 0$                 |      | 2    | mA   |
| I <sub>CEO</sub>   |                                      | TIP111                                  | V <sub>CE</sub> = 40 V, I <sub>B</sub> = 0         |      | 2    |      |
|  |                                      | TIP112                                  | $V_{CE} = 50 \text{ V}, I_{B} = 0$                 |      | 2    |      |
|  | Collector Cut-Off Current            | TIP110                                  | $V_{CB} = 60 \text{ V}, I_{E} = 0$                 |      | 1    | mA   |
| I <sub>CBO</sub>   |                                      | TIP111                                  | V <sub>CB</sub> = 80 V, I <sub>E</sub> = 0         |      | 1    |      |
|  |                                      | TIP112                                  | V <sub>CB</sub> = 100 V, I <sub>E</sub> = 0        |      | 1    |      |
| I <sub>EBO</sub>   | Emitter Cut-Off Current              |   | $V_{EB} = 5 \text{ V}, I_{C} = 0$                  |      | 2    | mA   |
| h <sub>FE</sub> DC Curre                                   | DC Current Coin                      | C. Current Coin                         |  | 1000 |      |      |
|  | DC Current Gain                      |   | $V_{CE} = 4 \text{ V}, I_{C} = 2 \text{ A}$        | 500  |      |      |
| V <sub>CE</sub> (sat) Collector-Emitter Saturation Voltage |                                      | $I_C = 2 \text{ A}, I_B = 8 \text{ mA}$ |  | 2.5  | V    |      |
| V <sub>BE</sub> (on)                                       | Base-Emitter On Voltage              |   | $V_{CE} = 4 \text{ V}, I_{C} = 2 \text{ A}$        |      | 2.8  | V    |
| C <sub>ob</sub>  | Output Capacitance                   |   | $V_{CB} = 10 \text{ V}, I_{E} = 0,$<br>f = 0.1 MHz |      | 100  | pF   |

#### Note:

1. Pulse test: pw  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%.

## **Typical Performance Characteristics**

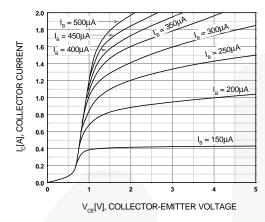


Figure 1. Static Characteristic

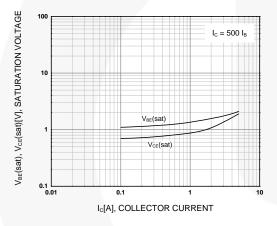


Figure 3. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

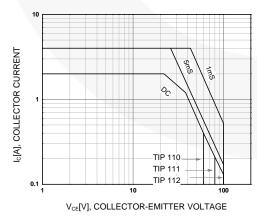


Figure 5. Safe Operating Area

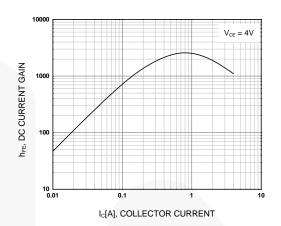
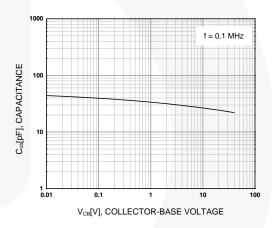


Figure 2. DC Current Gain



**Figure 4. Collector Output Capacitance** 

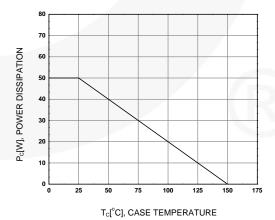
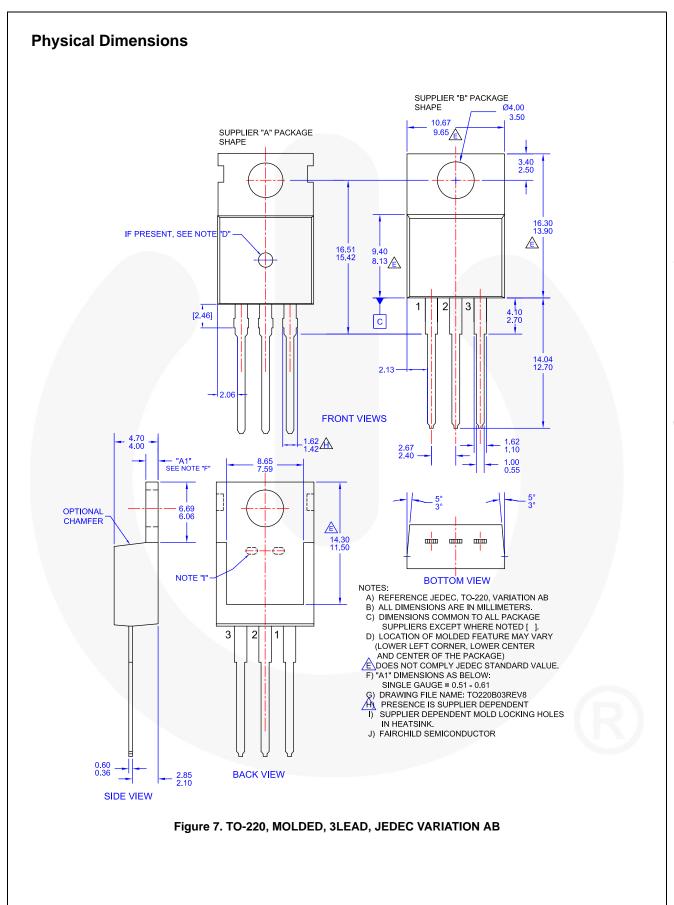


Figure 6. Power Derating







#### TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

 AccuPower™
 F-PFS™

 Awinda®
 FRFET®

 AX-CAP®∗
 Global Power Resource

 Stock
 Stock

BitSiC™ GreenBridge™ Build it Now™ Green FPS™

Current Transfer Logic™ ISOPLANAR™
DEUXPEED® Making Small St

DEUXPEED<sup>®</sup> Making Small Speakers Sound Louder
Dual Cool™ and Better™

EcoSPARK® MegaBuck™
EfficientMax™ MICROCOUPLER™
ESBC™ MicroFET™
MicroPak™

MicroPak2™ Fairchild® MillerDrive™ Fairchild Semiconductor® MotionMax™ FACT Quiet Series™ MotionGrid® FACT<sup>®</sup> FAST® MTi<sup>®</sup> MTx® FastvCore™ MVN® FFTBench™ mWSaver® **FPS™** 

OptoHiT™ OPTOLOGIC<sup>®</sup> OPTOPLANAR®

® PowerTrench® PowerXS™

Programmable Active Droop™

QFET<sup>®</sup>
QS™
Quiet Series™
RapidConfigure™

Saving our world, 1mW/W/kW at a time™

SignalWise™ SmartMax™ SMART START™

Solutions for Your Success™

Solutions for Yo SPM® STEALTH™ SuperFET® SuperSOT™-3 SuperSOT™-8 SupreMOS® SyncFET™ Sync-Lock™ SYSTEM GENERAL®

TinyBoost®
TinyBuck®
TinyCalc™
TinyLogic®
TINYOPTO™
TinyPower™
TinyPWM™
TinyWire™
TranSiC™

TriFault Detect™
TRUECURRENT®\*

µSerDes™

SerDes"
UHC®
Ultra FRFET™
UniFET™
VCX™
VisualMax™
VoltagePlus™
XS™
Xsens™

仙童™

\* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <a href="http://www.fairchildsemi.com">http://www.fairchildsemi.com</a>, FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OF CIRCUIT DESCRIBED HEREIN, NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

#### As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### PRODUCT STATUS DEFINITIONS

#### **Definition of Terms**

| Datasheet Identification | Product Status        | Definition  |
|--------------------------|-----------------------|---|
| Advance Information      | Formative / In Design | Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.   |
| Preliminary              | First Production      | Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design. |
| No Identification Needed | Full Production       | Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.   |
| Obsolete                 | Not In Production     | Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.  |

Rev. 172

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdt/Patent-Marking.pdf">www.onsemi.com/site/pdt/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and exp

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81–3–5817–1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Darlington Transistors category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below:

NJVMJD128T4G 281287X BDV64B NJVMJD117T4G LB1205-L-E 2N6053 MPSA14 TIP140 MPSA13 TIP127L-BP 2N6383

ULN2003ACM/TR 2N7371 2N6058 2N6059 2N6051 MJ2501 MJ3001 2SB1560 2SB852KT146B 2SD2560 TIP112TU BCV27

MMBTA13-TP MMSTA28T146 NTE2557 NJVNJD35N04T4G MPSA29-D26Z FJB102TM BSP61H6327XTSA1 BU941ZPFI

2SD1980TL NTE2350 NTE245 NTE246 NTE2649 NTE46 NTE98 ULN2003ADR2G NTE2344 NTE2349 NTE2405 NTE243 NTE244

NTE247 NTE248 NTE248 NTE253 NTE2548 NTE261